# NSN 5961-01-050-7042

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# Inclosure Material:

Ceramic

## **Overall Length:**

Between 0.633 inches and 0.643 inches

## **Overall Height:**

Between 0.125 inches and 0.135 inches

#### **Overall Width:**

Between 0.495 inches and 0.505 inches

## Mounting Facility Quantity:

1

#### Internal Configuration:

Junction contact

#### Electrode Internally-electrically Connected To Case:

Gate

#### **Mounting Method:**

Unthreaded hole

# Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

Between 120.00 milliamperes source cutoff current and 8.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

2.2 watts small-signal input power, common-collector absolute

### Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Terminal Type And Quantity:**

3 pin

#### **Specification Data:**

80131-release6403 professional/industrial association specification

#### Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

No

# Fiig:

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